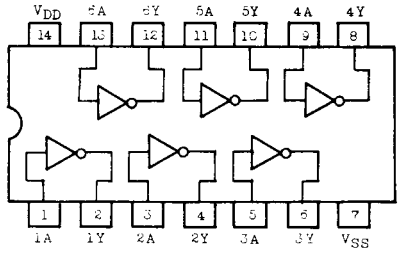
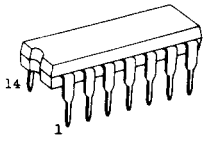
C²MOS DIGITAL INTEGRATED CIRCUIT
SILICON MONOLITHIC

TC40H004P/F

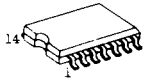
TC40H004 HEX INVERTER

PIN CONNECTION





DIP14(3D14A-P)

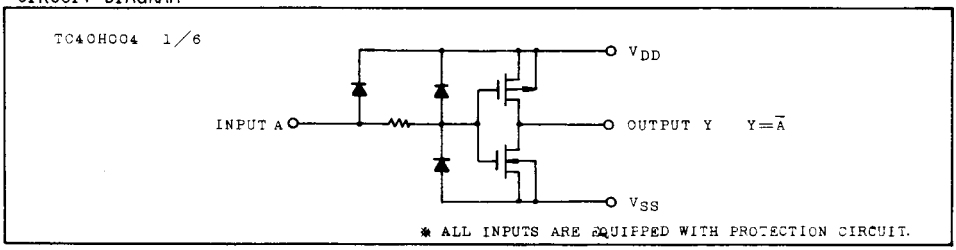


MFP14(F14GB-P)

MAXIMUM RATINGS

CHARACTERISTIC	SYMBOL	RATING	UNIT
Supply Voltage	V_{DD}	V_{SS}-0.5 ∿ V_{SS}+10	V
Input Voltage	V_{IN}	V_{SS}-0.5 ∿ V_{DD}+0.5	V
Output Voltage	V_{OUT}	V_{SS}-0.5 ∿ V_{DD}+0.5	V
Input Current	I_{IN}	±10	mA
Power Dissipation	P_D	300(DIP)/180(MFP)	mW
Storage Temperature	T_{stg}	-65 ∿ 150	°C
Lead Temp./Time	T_{sol}	260°C·10 sec	

CIRCUIT DIAGRAM



RECOMMENDED OPERATING CONDITIONS (V_{SS}=0.0V)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Supply Voltage	V_{DD}	-	2.0	-	8.0	V
Input Voltage	V_{IN}	-	0	-	V_{DD}	V
Operating Temperature	T_{opr}	-	-40	-	85	°C

TC40H004P/F

ELECTRICAL CHARACTERISTICS (V_{SS}=0.0V)

CHARACTERISTIC		SYMBOL	TEST CONDITION	V_{DD} (V)	-40°C		25°C			85°C		UNIT
					MIN.	MAX.	MIN.	TYP.	MAX.	MIN.	MAX.	
High Level Output Voltage		V_{OH}	$\|I_{OUT}\|<1\mu A$ $V_{IN}=V_{SS}$	5	4.95	-	4.95	5.0	-	4.95	-	V
Low Level Otuput Voltage		V_{OL}	$\|I_{OUT}\|<1\mu A$ $V_{IN}=V_{DD}$	5	-	0.05	-	0.0	0.05	-	0.05	
High Level Output Current		I_{OH}	V_{OH}=4.6V $V_{IN}=V_{SS}$	5	-0.52	-	-0.44		-	-0.36	-	mA
Low Level Output Current		I_{OL}	V_{OL}=0.4V $V_{IN}=V_{DD}$	5	1.4	-	1.1		-	0.8	-	
Input Voltage	High Level	V_{IH}	$\|I_{OUT}\|<1\mu A$ V_{OUT}=0.5V	5	4.0	-	4.0		-	4.0	-	V
	Low Level	V_{IL}	V_{OUT}=4.5V $V_{IN}=V_{SS},V_{DD}$	5	-	1.0	-		1.0	-	1.0	
Input Current	"H" Level	I_{IH}	V_{IH}=8.0V	8	-	0.3	-	10^{-5}	0.3	-	1.0	μA
	"L" Level	I_{IL}	V_{IL}=0.0V	8	-	-0.3	-	-10^{-5}	-0.3	-	-1.0	
Quiescent Supply Current		I_{DD}	*$V_{IN}=V_{SS},V_{DD}$	5	-	2.0	-	10^{-3}	2.0	-	10.0	μA

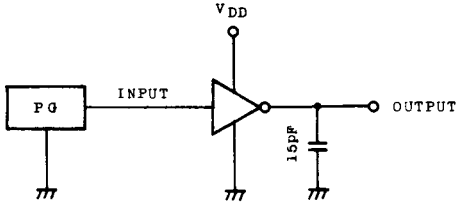
* All valid input combinations.

SWITCHING CHARACTERISTICS (Ta=25°C, V_{SS}=0.0V, C_L=15pF)

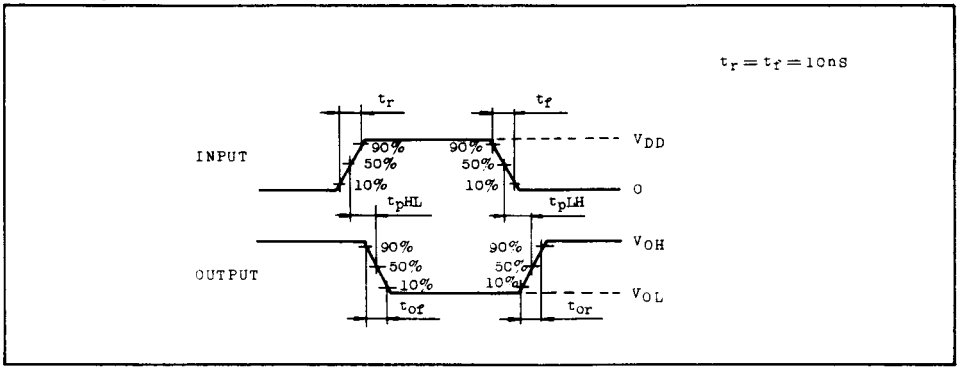
CHARACTERISTIC		SYMBOL	TEST CONDITION	V_{DD}(V)	MIN.	TYP.	MAX.	UNIT
Output Rise Time		t_{or}	Circuit 1	5	-	14	30	ns
Output Fall Time		t_{of}	Circuit 1	5	-	11	30	
Propagation Delay Time	(Low-High)	t_{pLH}	Circuit 1	5	-	15	20	ns
	(High-Low)	t_{pHL}		5	-	13	20	
Input Capacitance		C_{IN}			-	5		pF

SWITCHING TIME TEST CIRCUIT

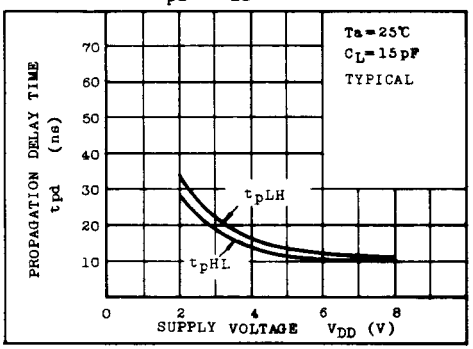
CIRCUIT 1.



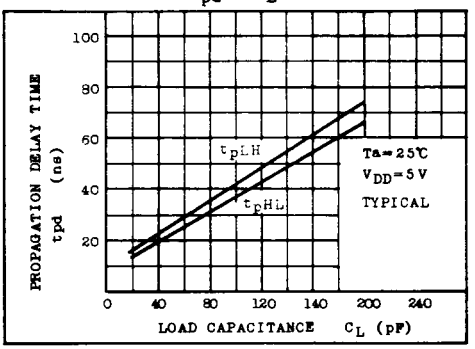
SWITCHING TIME TEST WAVEFORM



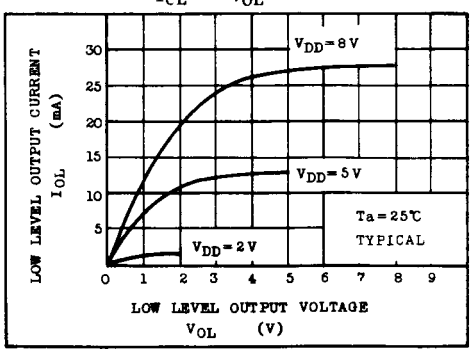
t_{pd} - V_{DD}



t_{pd} - C_L



I_{CL} - V_{OL}



I_{OH} - (V_{DD} - V_{OH})